

Hermetic Infrared Emitting Diode

OP230 Series

Obsolete (OP231W)



Features:

- Focused and non-focused optical light pattern
- Enhanced temperature range
- TO-46 hermetically sealed package
- Mechanically and spectrally matched to other Optek devices
- Choice of power ranges
- Choice of narrow or wide irradiance pattern

Description:

Each device in this series is a gallium aluminum arsenide (GaAlAs) infrared emitting diode, mounted in a hermetic metal TO-46 housing. The gallium aluminum arsenide feature provides a higher radiated output than gallium arsenide at the same forward current.

Each **OP231**, **OP232**, **OP233**, **OP234** and **OP235** device is lensed to provide a narrow beam angle (18°) between half power points. The 890 nm wavelength closely matches the spectral response of silicon phototransistors, while the narrow beam angle – combined with the specified radiant intensity of the OP231 series – facilitates easy design in beam interrupt applications in conjunction with the OP800 or OP598 series photosensors. *The OP231 series is mechanically and spectrally matched to OP800, OP593 and OP598 phototransistors.*

Each **OP232W**, **OP233W**, **OP234W** and **OP235W** device is lensed to provide a wide beam angle (50°) between half power points. The 890 nm wavelength closely matches the spectral response of silicon photo-transistors, while the wide beam angle provides relatively even illumination over a large area. *The OP23xW series is mechanically and spectrally matched to the OP800WSL and OP830SL series devices.*

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor

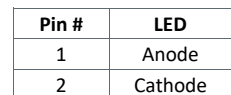
Ordering Information					
Part Number	LED Peak Wavelength	Output Power (mW/cm ²) Min / Max	Total Beam Angle	Lead Length	
OP231	890 nm	1.5 / NA	18°	0.50"	
OP232		2.0 / 6.0			
OP233		3.0 / NA			
OP234	850 nm	5.0 / NA	50°		
OP235		6.0 / NA			
OP231W (Obsolete)	890 nm	1.5 / NA			
OP232W		3.5 / 7.0			
OP233W		5.0 / NA			
OP234W	850 nm	5.0 / NA			
OP235W		6.0 / NA			

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

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Electrical Specifications

Electrical Characteristics ($T_A = 25^\circ \text{C}$ unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
$E_{E(APT)}$	Apertured Radiant Incidence					
	OP231	1.5	-	-	mW/ cm ²	$I_F = 100 \text{ mA}^{(3)(4)}$ Aperture = 0.250" Distance = 1.429"
	OP232	2.0	-	6.0		
	OP233	3.0	-	-		
	OP234	5.0	-	-		
	OP235	6.0	-	-		
	OP232W	3.5	-	7.0	mW/ cm ²	$I_F = 100 \text{ mA}^{(3)(4)}$ Aperture = 0.250" Distance = 0.466"
	OP233W	5.0	-	-		
	OP234W	5.0	-	-		
	OP235W	6.0	-	-		
P_O	Radiant Power Output					
	OP231	-	6.0	-	mW	$I_F = 100 \text{ mA}^{(3)}$
	OP232	-	8.0	-		
	OP233	-	10.0	-		
V_F	Forward Voltage	-	-	2.0	V	$I_F = 100 \text{ mA}^{(3)}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2.0 \text{ V}$
λ_P	Wavelength at Peak Emission					
	OP231, OP232, OP233	-	890	-	nm	$I_F = 10 \text{ mA}$
	OP234, OP235	-	850	-		
β	Spectral Bandwidth between Half Power Points	-	80	-	nm	$I_F = 10 \text{ mA}$
$\Delta\lambda_P/\Delta T$	Spectral Shift with Temperature	-	+0.30	-	nm/ $^\circ\text{C}$	$I_F = \text{Constant}$
θ_{HP}	Emission Angle at Half Power Points					
	OP231 - OP235	-	18	-	Degree	$I_F = 100 \text{ mA}$
	OP231W - OP235W	-	50	-		
t_r	Output Rise Time	-	500	-	ns	$I_{F(PK)} = 100 \text{ mA}$, $PW = 10 \mu\text{s}$, and D.C. = 10.0 %
t_f	Output Fall Time	-	250	-	ns	

Notes:

1. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
2. Derate linearly 2.0 mW/ $^\circ\text{C}$ above 25°C .
3. Measurement made with 100 μs pulse measured at the trailing edge of the pulse with a duty cycle of 0.1 % and an $I_F = 100 \text{ mA}$.
4. For the OP231 series, $E_{E(APT)}$ is a measurement of the average radiant intensity within the cone formed by the measurement surface, a radius of 1.429" (36.30 mm) measured from the lens side of the tab to the sensing surface and a sensing surface of 0.250" (6.35 mm) in diameter forming a 10° cone. For the OP23xW series, $E_{E(APT)}$ is a measurement of the average radiant intensity within the cone formed by the measurement surface, a radius of 0.466" (11.84 mm) measured from the lens side of the tab to the sensing surface and a sensing surface of 0.250" (6.35 mm) in diameter forming a 10° cone. $E_{E(APT)}$ is not necessarily uniform within the measured area.

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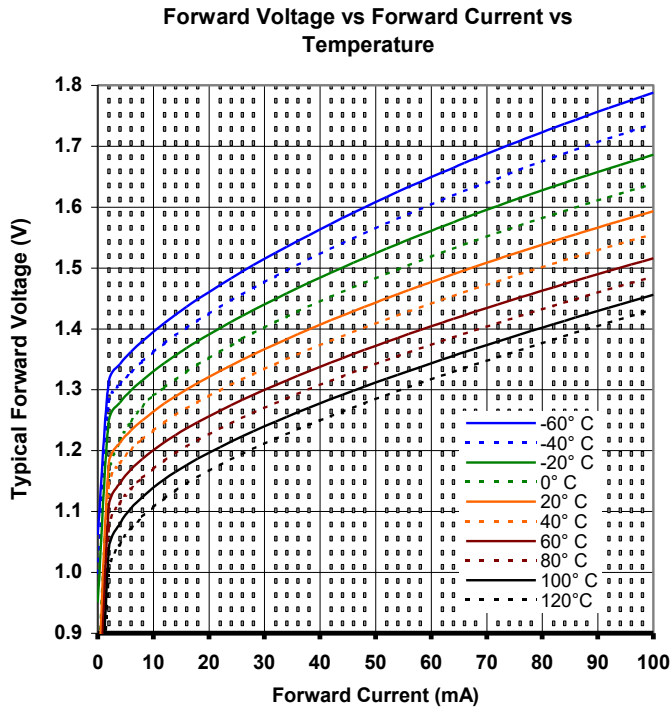
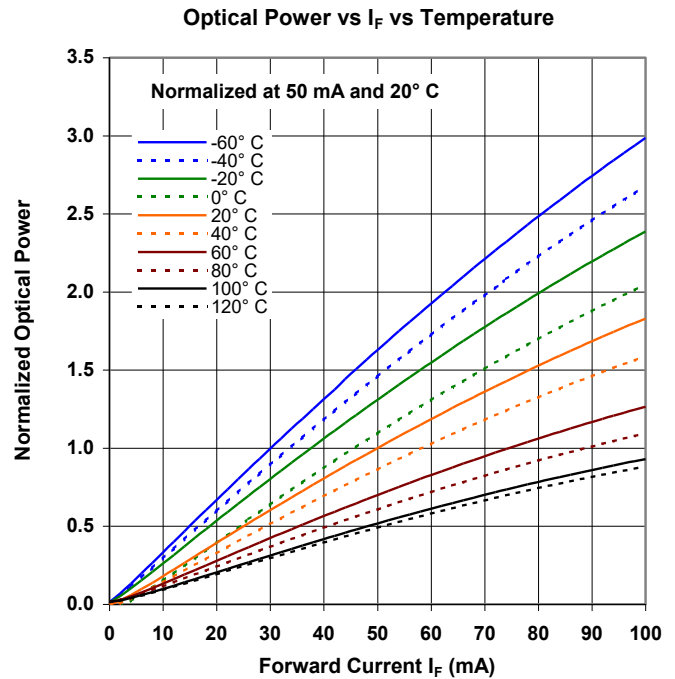
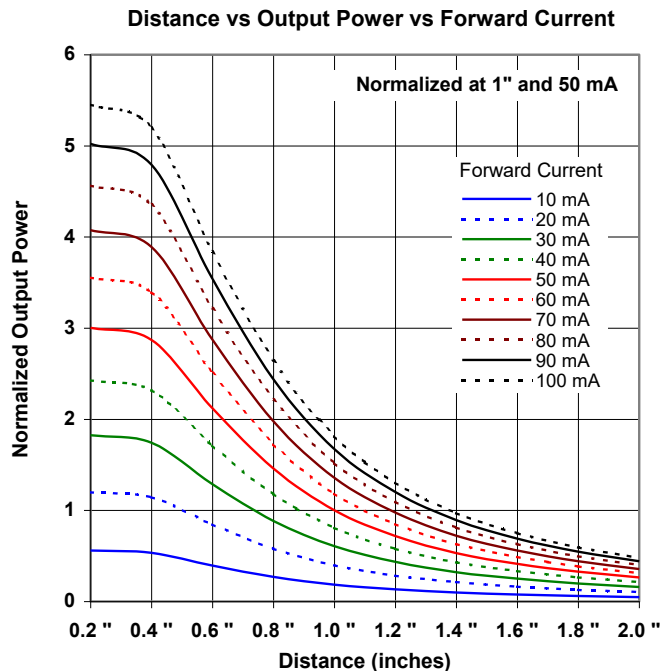
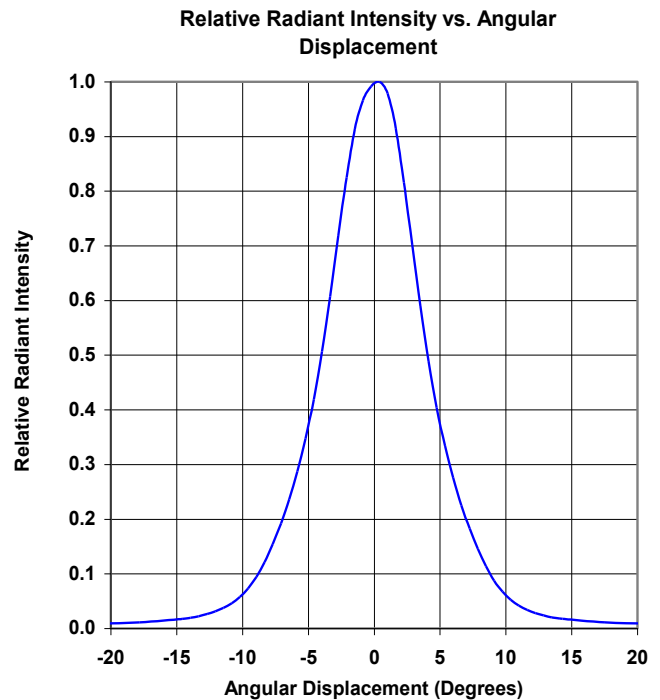
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Performance

OP231, OP232, OP233 (including "W" devices)



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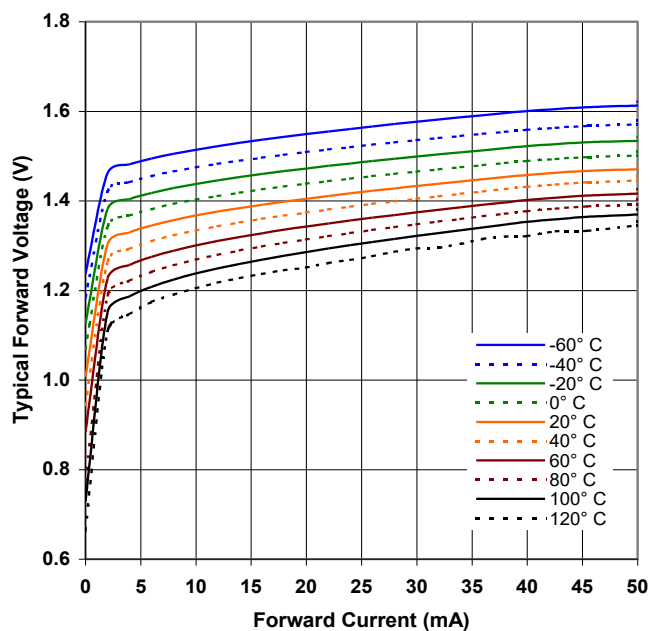
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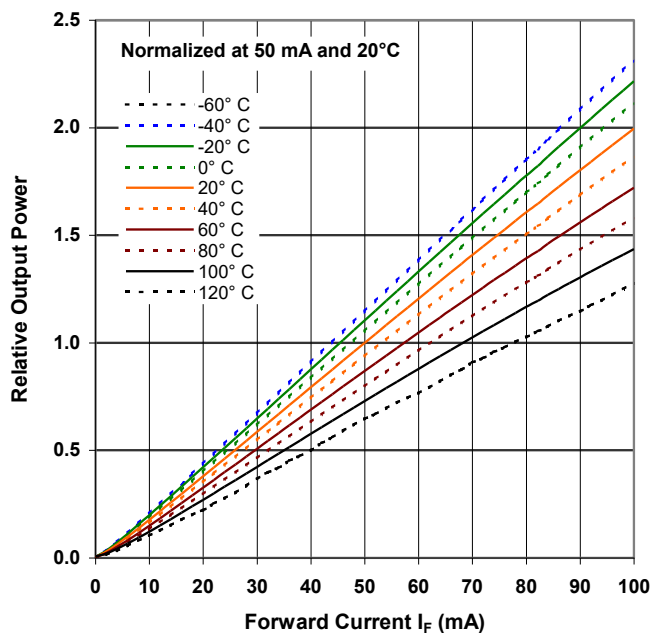
Performance

OP234, OP234W

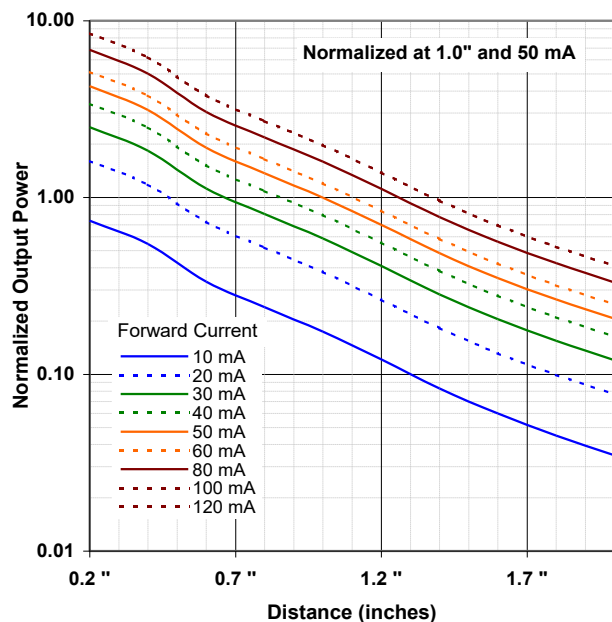
Forward Voltage vs Forward Current vs Temperature



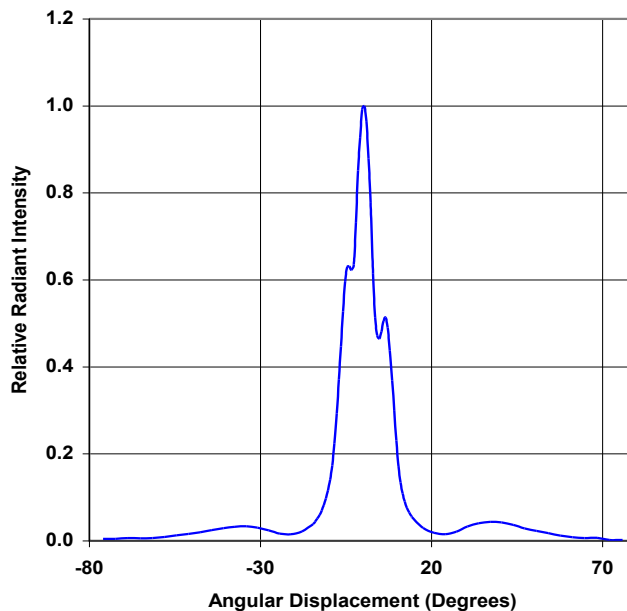
Optical Power vs Forward Current vs Temperature



Distance vs Output Power vs Forward Current



Relative Radiant Intensity vs Angular Displacement



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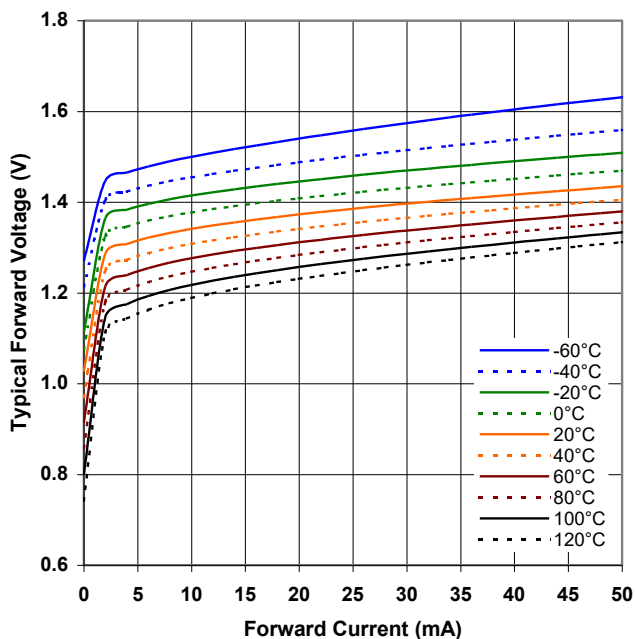
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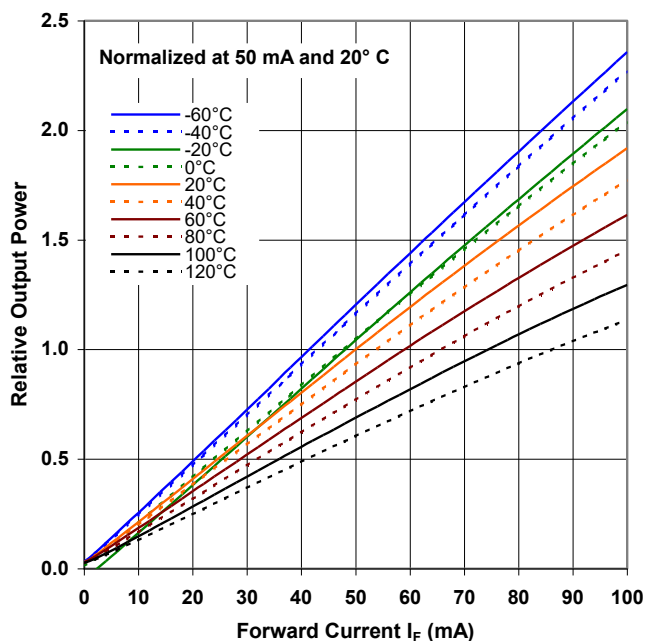
Performance

OP235, OP235W

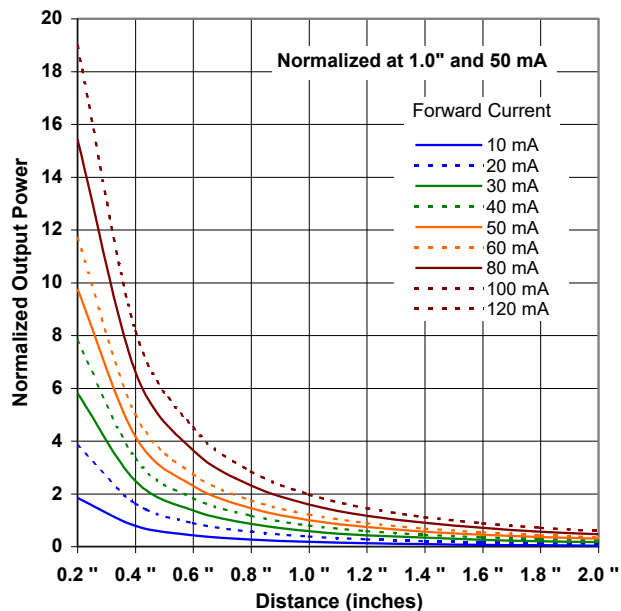
Forward Voltage vs Forward Current vs Temperature



Optical Power vs Forward Current vs Temperature



Distance vs Output Power vs Forward Current



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